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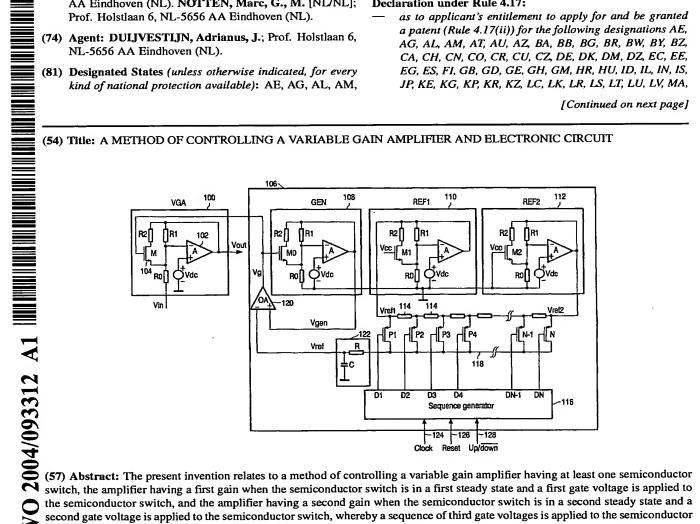
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Declaration under Rule 4.17:

as to applicant's entitlement to apply for and be granted a patent (Rule 4.17(ii)) for the following designations AE,



the semiconductor switch, and the amplifier having a second gain when the semiconductor switch is in a second steady state and a second gate voltage is applied to the semiconductor switch, whereby a sequence of third gate voltages is applied to the semiconductor switch to transition between the first and second gains.



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